

PROCEEDINGS OF SPIE

High-Power Diode Laser Technology and Applications IX

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Editor

23–25 January 2011
San Francisco, California, United States

Sponsored and Published by
SPIE

Volume 7918

Proceedings of SPIE, 0277-786X, v. 7918

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

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Please use the following format to cite material from this book:

Author(s), "Title of Paper," in *High-Power Diode Laser Technology and Applications IX*, edited by Mark S. Zediker, Proceedings of SPIE Vol. 7918 (SPIE, Bellingham, WA, 2011) Article CID Number.

ISSN 0277-786X

ISBN 9780819484550

Published by

SPIE

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

SPIE.org

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